



SOT-323 Plastic-Encapsulate Transistor (NPN)

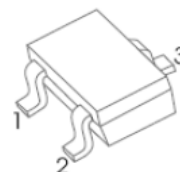
Feature

- Complementary to MMST3906
- Power Dissipation of 200mW
- High Stability and High Reliability

Mechanical Data

- SOT-323 Small Outline Plastic Package
- Epoxy UL: 94V-0
- Mounting Position: Any

SOT-323



1. BASE
2. EMITTER
3. COLLECTOR

Marking: K2N

Maximum Ratings & Thermal Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V_{CEO}	40	V
Emitter -Base Voltage	V_{EBO}	5	V
Collector Current-Continuous	I_C	200	mA
Collector Power Dissipation	P_C	200	mW
Junction Temperature	T_j	-55 to +150	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^{\circ}\text{C}$
Thermal resistance from junction to ambient	$R_{\theta JA}$	625	$^{\circ}\text{C/W}$

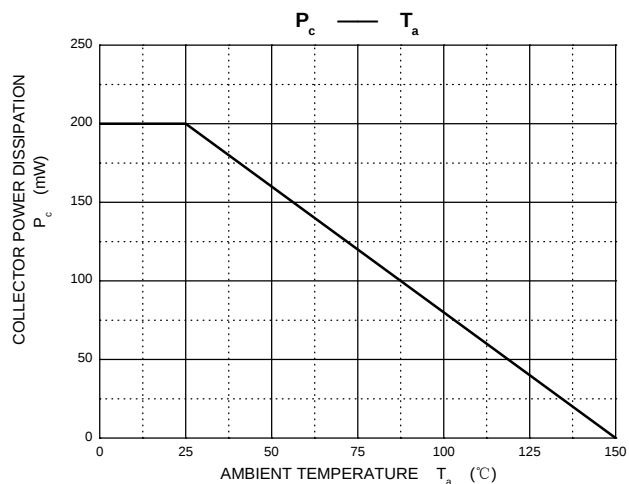
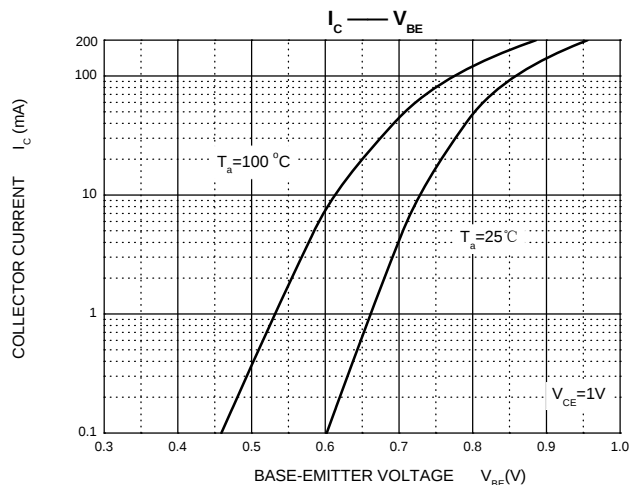
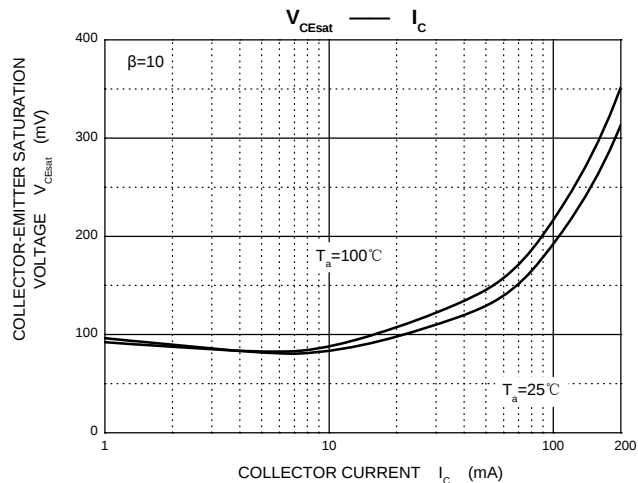
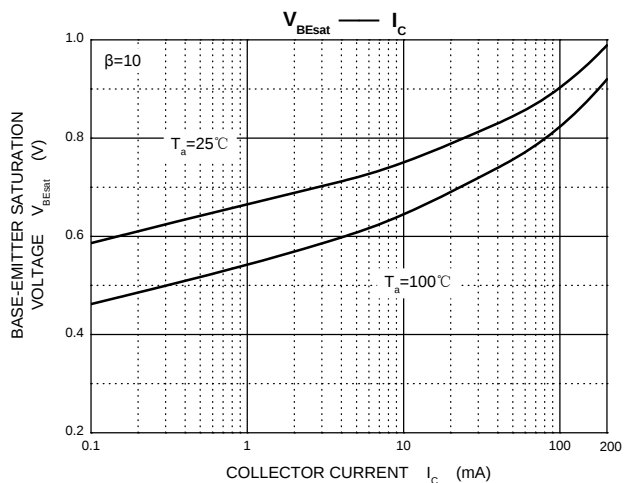
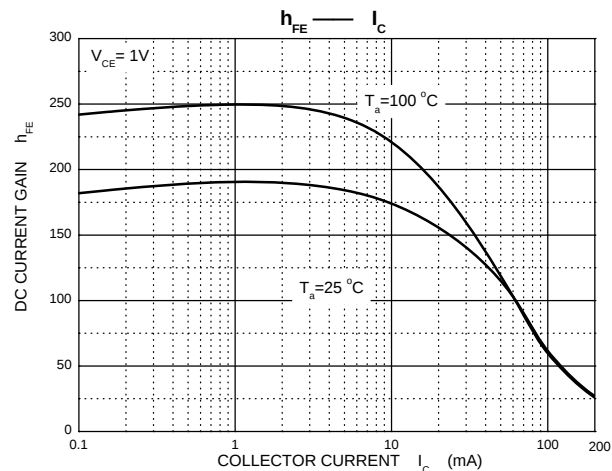
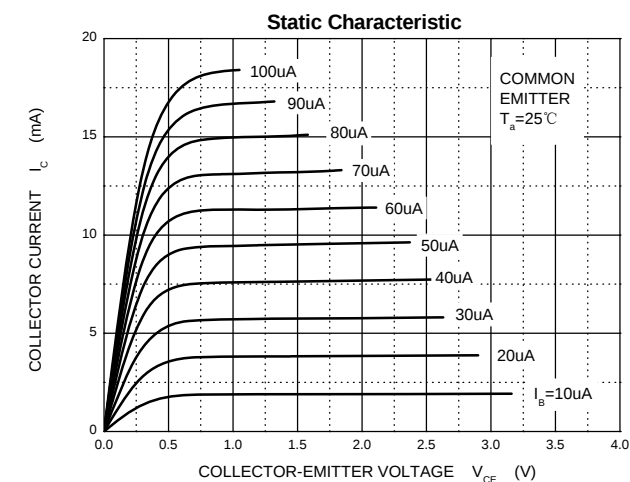
Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}^*$	$I_C=10\mu\text{A}$, $I_E=0$	60			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}^*$	$I_C=1\text{mA}$, $I_B=0$	40			V
Emitter-base breakdown voltage	$V_{(BR)EBO}^*$	$I_E=10\mu\text{A}$, $I_C=0$	5			V
Collector cut-off current	I_{CBO}^*	$V_{CB}=60\text{V}$, $I_E=0$			60	nA
Collector cut-off current	I_{CEX}	$V_{CE}=30\text{V}$, $V_{BE(off)}=3\text{V}$			50	nA
DC current gain	h_{FE}^*	$V_{CE}=1\text{V}$, $I_C=100\mu\text{A}$	40			
		$V_{CE}=1\text{V}$, $I_C=1\text{mA}$	70			
		$V_{CE}=1\text{V}$, $I_C=10\text{mA}$	100		300	
		$V_{CE}=1\text{V}$, $I_C=50\text{mA}$	60			
Collector-emitter saturation voltage	$V_{CE(sat)}^*$	$I_C=10\text{mA}$, $I_B=1\text{mA}$			0.25	V
		$I_C=50\text{mA}$, $I_B=5\text{mA}$			0.3	V
Base-emitter saturation voltage	$V_{BE(sat)}^*$	$I_C=10\text{mA}$, $I_B=1\text{mA}$			0.85	V
		$I_C=50\text{mA}$, $I_B=5\text{mA}$			0.95	V
Transition frequency	f_T	$V_{CE}=20\text{V}$, $I_C=10\text{mA}$, $f=100\text{MHz}$	300			MHz
Collector output capacitance	C_{ob}	$V_{CB}=5\text{V}$, $I_E=0$, $f=1\text{MHz}$			4	pF
Collector output capacitance	C_{ib}	$V_{EB}=0.5\text{V}$, $I_E=0$, $f=1\text{MHz}$			8	pF
Delay time	t_d	$V_{CC}=3\text{V}$, $V_{BE(off)}=0.5\text{V}$			35	ns
Rise time	t_r	$I_C=10\text{mA}$, $I_{B1}=1\text{mA}$			35	ns
Storage time	t_s	$V_{CC}=3\text{V}$, $I_C=10\text{mA}$, $I_{B1}=I_{B2}=1\text{mA}$			225	ns
Fall time	t_f				75	ns

*Pulse test: pulse width $\leq 300\mu\text{s}$, duty cycles $\leq 2.0\%$.

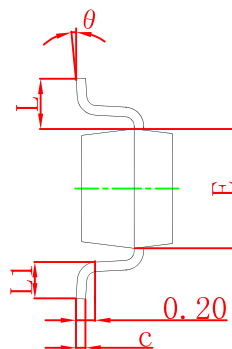
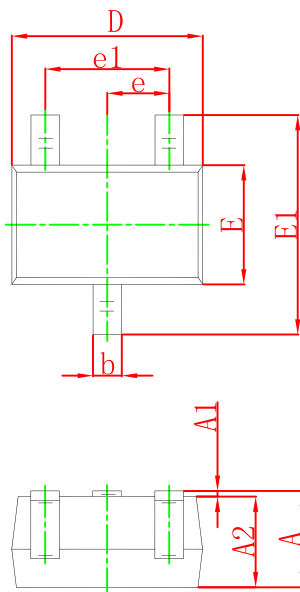


Typical Characteristics



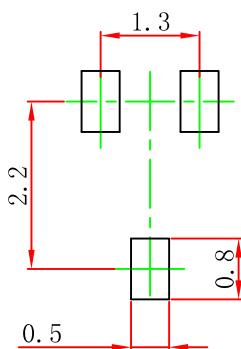


SOT-323 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650 TYP		0.026 TYP	
e1	1.200	1.400	0.047	0.055
L	0.525 REF		0.021 REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

SOT-323 Suggested Pad Layout



Notes:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.